

Characterization of Interconnects

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Disruptive Acceleration Science

Outcomes and Impact

Awarded FY22 Core Modelling Call

Period of Performance: 2.5 Y

Funding: \$1.277 M

Capability Goals

- Evaluate strengths and weaknesses of modern cell interconnect designs with combined-accelerated stress testing (C-AST) to screen multiple climates along with finite element and failure analysis to determine potential for a 50-year life. Field validation in Alaska (cold) and Arizona (Hot)

Accomplishments


- Surveyed new interconnect technologies
- Acquired five types of modules with novel interconnects and started testing
- Developing Remote-Dynamic Mechanical Acceleration tool
- Characterized low-temperature solder wire interconnects, their geometry and materials
- Created FEA mesh for low-temperature soldered wire interconnected cells and module

Outcomes and Impact

- Development of accelerated testing capabilities to de-risk cell interconnects, identify weaknesses not captured by existing standardized tests, and validate interconnects for a 50-year life
- Develop methods of characterization to assess the degradation of interconnects
- Enable predictive rate models with material forensics and FEA
- Show C-AST's ability to find interconnect failures and benchmark it relative to other test methods

Project Overview

ACCELERATED TESTING



C-AST: stress factors applied at extremes and in combinations of natural environment:

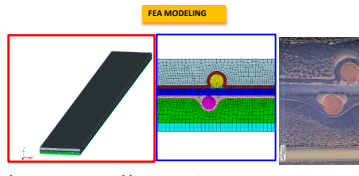
- Heat
- Light
- Humidity
- Condensing
- Non-condensing
- Mechanical pressure
- System voltage

Focus on characterization of low-temperature solder wire interconnects

Capability developed for metallographic analysis on 2018 generation modules with low-temperature solder-interconnects

- Cu wire \varnothing (typically 200-300 μm)
- Peripheral solder coating (SnIn \rightarrow SnBi)
- Polymer foil materials (recently PET & POE)

FEA MODELING




Model for full wire-interconnected module

Geometries and boundary conditions allow wire movement over a module exposure to be calculated and used as a metric for degradation by metallization wearing

low-temperature solder wire interconnects along a half-cut cell

Modeled geometries and materials correspond to those measured

ACCELERATED TESTING



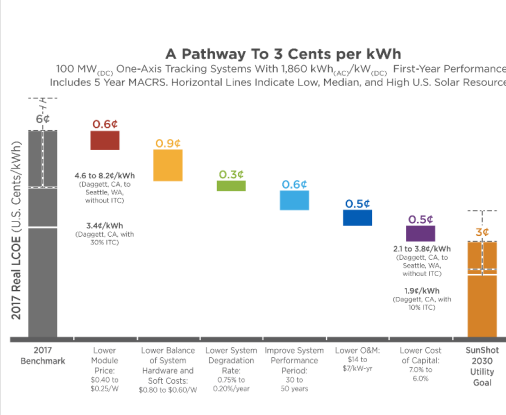
Remote Source Dynamic Mechanical Acceleration Tool

By separating the speaker enclosure from the module, and transmitting the induced pressure wave through a tube, the module may be placed within an environmental chamber while the speaker enclosure remains in ambient laboratory conditions.

Cost Drivers

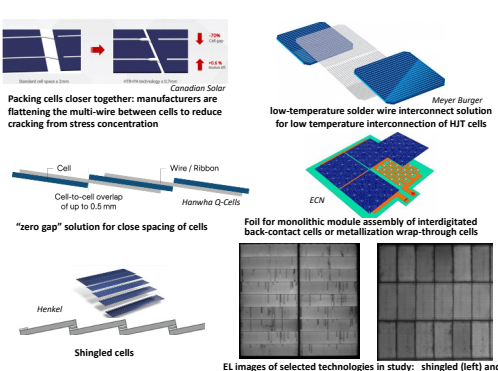
A Pathway To 3 Cents per kWh

100 MW_{DC} One-Axis Tracking Systems With 1,860 kWh_{AC}/kW_{DC} First-Year Performance. Includes 5 Year MACRS. Horizontal Lines Indicate Low, Median, and High U.S. Solar Resources.



| Year/Category | Value (U.S. Cents/kWh) |
|---|------------------------|
| 2017 Benchmark | 6c |
| Lower Module Price | 4.6 to 8.26/kWh |
| Lower Balance of System Hardware and Soft Costs | 3.44/kWh |
| Lower System Degradation Rate | 0.3c |
| Improve System Performance Period | 0.6c |
| Lower O&M | 0.5c |
| Lower Cost of Capital | 0.5c |
| SunShot 2030 Utility Goal | 3c |

Evaluation of Emerging Module Interconnect Technologies



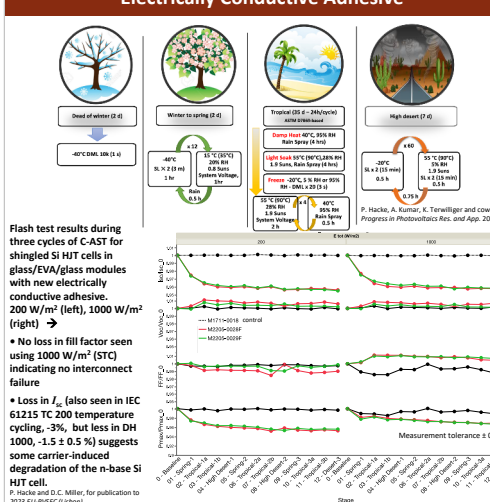
- Canadian Solar
- Meyer Burger
- Hamawa Q-Cells
- ECN
- Henkel
- Shingled cells

"zero gap" solution for close spacing of cells

Foil for monolithic module assembly of interdigitated back-contact cells or metallization wrap-through cells

EL Images of selected technologies in study: shingled (left) and low-temperature wire interconnect (right)

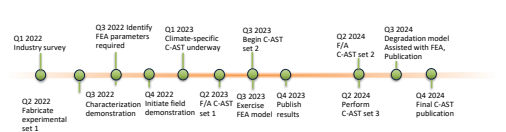
Combined-Accelerated Stress Testing: Shingled Cells with Electrically Conductive Adhesive



Flash test results during three cycles of C-AST for shingled Si HIT cells in glass/EVA/glass modules with new electrically conductive adhesive. 200 W/m² (left), 1000 W/m² (right) \rightarrow

- No loss in fill factor seen using 1000 W/m² (STC) indicating no interconnect failure
- Loss in I_{sc} (also seen in IEC 61215 TC 200 Temperature cycling, -3%, but less in DH 1000, -1.5 \pm 0.5%) suggests some carrier-induced degradation of the n-base Si HIT cell.

Timeline



- Q2 2022: Fabricate experimental set 1
- Q3 2022: Characterization demonstration
- Q4 2022: Characterization initiate field demonstration
- Q1 2023: Climate-specific C-AST underway
- Q2 2023: FEA C-AST
- Q3 2023: Begin C-AST set 2
- Q4 2023: Perform FEA model results
- Q1 2024: Perform C-AST set 3
- Q2 2024: Final C-AST publication
- Q3 2024: Degradation model Assisted with FEA, Publication
- Q4 2024: Final C-AST publication

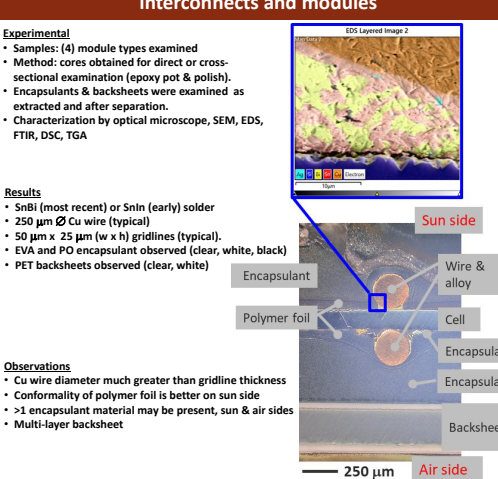
Characterization of the low-temperature solder wire interconnects and modules

Experimental

- Samples: (4) module types examined
- Method: cores obtained for direct or cross-sectional examination (epoxy pot & polish).
- Encapsulants & backsheets were examined as extracted and after separation.
- Characterization by optical microscope, SEM, EDX, FTIR, DSC, TGA

Results (most recent) or SnIn (early) solder

- 250 μm \varnothing Cu wire (typical)
- 50 μm x 25 μm (w x h) gridlines (typical).
- EVA and PO encapsulant observed (clear, white, black)
- PET backsheets observed (clear, white)

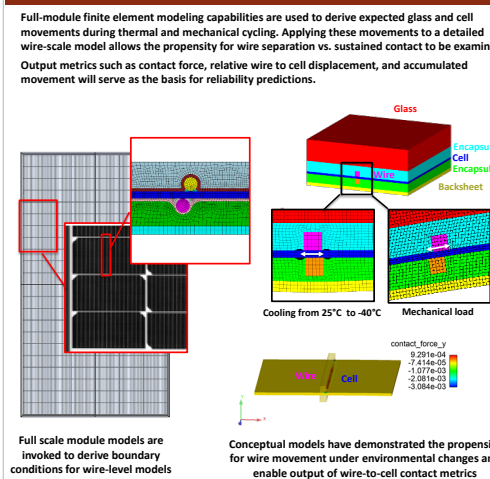


Observations

- Cu wire diameter much greater than gridline thickness
- Conformality of polymer foil is better on sun side
- >1 encapsulant material may be present, sun & air sides
- Multi-layer backsheet

Wire Interconnect Degradation Modeling Methodology

Full-module finite element modeling capabilities are used to derive expected glass and cell movements during thermal and mechanical cycling. Applying these movements to a detailed wire-scale model allows the propensity for wire separation vs. sustained contact to be examined. Output metrics such as contact force, relative wire to cell displacement, and accumulated movement will serve as the basis for reliability predictions.



Full scale module models are invoked to derive boundary conditions for wire-level models

Conceptual models have demonstrated the propensity for wire movement under environmental changes and enable output of wire-to-cell contact metrics

Focus: low-temperature soldered wire interconnects

Hypothesis

Considering the lower temperature melting alloys used with low-temperature wire interconnects (as used with Si HIT cells), the degradation of such interconnects is NOT accelerated by thermal cycling in the same way as traditional Pb-based solder interconnects. Rather, the mechanical nature of their connection to the cell metallization may be degraded by mechanical wear [1,2].

Approach

- A parallel experimental and modeling effort will elucidate if and how multi-wire interconnects are degraded by mechanical wear.
- The modeling effort will quantify ribbon to gridline movement under mechanical and thermal loading.
- The experimental effort will seek to induce mechanical wear of multi-wire interconnects with targeted mechanical cyclic load testing as well Remote Source Dynamic Mechanical Acceleration and extended IEC 61215 temperature cycling

[1] Spinella and N. Bosco, "Thermo-mechanical fatigue resistance of low temperature solder for multiwire interconnects in photovoltaic modules," Sol. Energy Mater. Sol. Cells, vol. 225, no. January, p. 111024, 2021, doi:10.1016/j.solmat.2021.111024

[2] L. Spinella, K. Teweliger, P. Walker, G. Pierre, C. S. Jiang and N. Bosco, "Reliability Implications of Solder in Multiwire Modules under Dynamic Mechanical Loading," 2021 IEEE 48th Photovoltaic Specialists Conference (PVSC), 2021, pp. 0108-0111, doi:10.1109/PVSC43889.2021.9518568

Capability Development: Remote Source Dynamic Mechanical Acceleration (DMX)

Experiment

Modules will be exposed to isothermal, cyclic mechanical load testing as interconnect degradation is monitored. For this program, the next generation of DMX has been developed to allow for both:

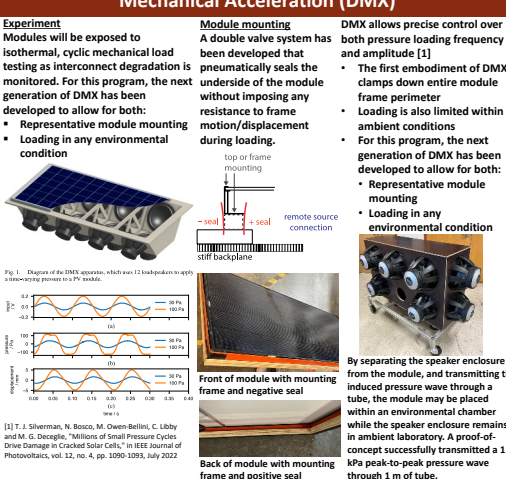
- Representative module mounting
- Loading in any environmental condition

Module mounting

A double valve system has been developed that pneumatically seals the underside of the module without imposing any resistance to frame motion/displacement during loading.

DMX allows precise control over both pressure loading frequency and amplitude [1]

- The first embodiment of DMX clamps down entire module frame perimeter
- Loading is also limited within ambient conditions
- For this program, the next generation of DMX has been developed to allow for both:
 - Representative module mounting
 - Loading in any environmental condition



By separating the speaker enclosure from the module, and transmitting the induced pressure wave through a tube, the module may be placed within an environmental chamber while the speaker enclosure remains in ambient laboratory. A proof-of-concept successfully transmitted a 1 kPa peak-to-peak pressure wave through 1 m of tube.

[1] T. Silverman, N. Bosco, M. Owen-Bellini, C. Libby and M. G. Degele, "Millions of Small Pressure Cycles Drive Damage in Cracked Solar Cells," in IEEE Journal of Photovoltaics, vol. 12, no. 4, pp. 1096-1099, July 2022